

A New Mean-Field Theory of the Kondo Resonance at Finite Bias

Jung Hoon Han

Department of Physics, SungKyunKwan University, Suwon 440-746, Korea

We introduce a new slave-boson mean-field treatment of the Kondo effect in a quantum dot attached to the leads, when the bias voltage across the leads is finite. The model employs two slave boson and two pseudo-fermion operators to express the localized electron. The solution of the mean-field equations gives in general two resonance peaks pinned to the chemical potential of each lead. The Kondo temperature is shown to scale as $\min(T_K^*, (T_K^*)^2/V)$, where T_K^* is the Kondo temperature at equilibrium, and V is the chemical potential difference of the leads.

The realization of Kondo resonance in a single molecule coupled to metallic leads offers a prime example of the many-body correlation effect at work on the nanometer scale [1]. The rapid advance in the fabrication technology of molecular-scale systems with current-carrying capability will produce growing opportunity to observe Kondo effect in a more intricate setup. On the theoretical side, it is important to develop tools suitable to describe Kondo phenomena in situations of increasing complexity.

The Kondo effect in a quantum dot coupled to metallic reservoir has been thoroughly studied, and many theoretical tools are available [2]. The formation of a resonance state at low temperature (Abrikosov-Suhl resonance) at the Fermi level of the host metal can be understood as a consequence of hybridization between a localized electron and the host electrons. The slave-boson theory captures many of the essential features of the Kondo resonance in the so-called Fermi-liquid regime [3]. For a quantum dot coupled to leads with different chemical potentials, *i.e.* $\mu_L \neq \mu_R$ where μ_L and μ_R are chemical potentials of the left and the right leads, however, there is a discrepancy in the outcome of the slave-boson mean-field theory (SBMFT) (predicting a single Kondo resonance) [4] and that of equation-of-motion (EOM) or non-crossing-approximation (NCA) theories (predicting a splitting of Kondo resonances) [2].

It is important to resolve this discrepancy fully, in view of the simplicity (hence its utility) of SBMFT with which to capture essential features of the Kondo physics. It will be desirable if the outcome of the mean-field theory can be made to agree with that of the more advanced techniques such as NCA or EOM methods. In this paper, we assume that the predictions of the NCA/EOM is indeed correct [5], and offer a new version of SBMFT that gives rise to split Kondo peaks. We conclude, on the basis of the new mean-field theory, that (1) the spectral function of the quantum dot has resonances pinned at the chemical potentials of each lead, (2) the Kondo temperature scales as $\min(T_K^*, (T_K^*)^2/V)$ where T_K^* is the Kondo temperature in the case of un-biased leads coupled to the dot, and V is the chemical potential difference of the leads. In the following we present the mathematical formulation of the theory and discuss physical consequences of the solution that emerges.

A quantum dot coupled to two leads via tunnelling may be modelled by the Hamiltonian

$$H = H_L + H_R + H_d + H_T \quad (1)$$

where the lead, the dot, and the tunnelling parts are

$$\begin{aligned} H_{L(R)} &= \sum_{k \in L(R), \sigma} (\epsilon_k - \mu_{L(R)}) c_{L(R)k\sigma}^+ c_{L(R)k\sigma} \\ H_d &= -\epsilon_d \sum_{\sigma} d_{\sigma}^+ d_{\sigma} + U n_d (n_d - 1) \\ H_T &= V_L \sum_{k \in L, \sigma} c_{Lk\sigma}^+ d_{\sigma} + V_R \sum_{k \in R, \sigma} c_{Rk\sigma}^+ d_{\sigma} + h.c. \end{aligned} \quad (2)$$

Tunnelling amplitude to each lead is given by V_L and V_R while the density of states of leads are assumed to be constant, ρ_L and ρ_R respectively. We consider the case where the bare energy level of the dot $-\epsilon_d (< 0)$ and the energy of double occupancy $U - \epsilon_d (> 0)$ are both large (Kondo regime).

The d -level operator d_{σ}^+ in the $U \rightarrow \infty$ limit is really $d_{\sigma}^+ = |\sigma\rangle\langle e|$, taking an empty state ($|e\rangle$) into a singly occupied state of spin σ ($|\sigma\rangle$), because doubly-occupied state is energetically forbidden. Commutation relations for d_{σ} thus differ from the canonical one:

$$\{d_{\sigma}, d_{\sigma}^+\} = 1 - d_{-\sigma}^+ d_{-\sigma}, \quad \{d_{\sigma}, d_{-\sigma}^+\} = d_{-\sigma}^+ d_{\sigma}. \quad (3)$$

In the usual slave-boson approach, the localized electron operator d_{σ} is replaced by $b^+ f_{\sigma}$ with b and f_{σ} being the standard boson and fermion operators. Commutation relations, Eq. (3), are recovered provided we require $b^+ b + \sum_{\sigma} f_{\sigma}^+ f_{\sigma} = 1$. The d_{σ} operators in the Hamiltonian are replaced by an equivalent expression, $d_{\sigma} \rightarrow b^+ f_{\sigma}$, while the constraint is included in the form of a Lagrange multiplier,

$$H \rightarrow H' = H + \lambda (b^+ b + \sum_{\sigma} f_{\sigma}^+ f_{\sigma} - 1). \quad (4)$$

The free parameters λ and b are self-consistently determined by the condition

$$\frac{\partial \langle H' \rangle}{\partial \lambda} = 0 = \frac{\partial \langle H' \rangle}{\partial b}. \quad (5)$$

The stationary state solution describes a narrow resonance state formed at the chemical potential of the lead

and gives a quantitative estimate of the width of the resonance that is also associated with the Kondo temperature T_K^* .

The same approach was adapted by Aguado and Langreth (AL) to the non-equilibrium case, $\mu_L \neq \mu_R$ [4]. One finds in this case that a single Kondo resonance state is formed at the energy level between the chemical potentials of each lead. In physical terms, the chemical potentials of the leads are “averaged over”, before an interaction with the localized electron is considered.

The root of the Abrikosov-Suhl resonance is the high-order virtual hopping process that in effect exchanges spins between the lead electrons and the localized electron. When more than one lead is attached to a dot, it appears that a correct picture is to view such hopping processes as occurring independently with respect to each lead, as far as one can ignore a direct interaction between the leads. Naturally, then, the resonance state will have to be formed for each lead, at the chemical potential of the corresponding lead. Motivated by this picture, let us write the d -level electron operator as

$$d_\sigma = \alpha b_1^+ f_{1\sigma} + \beta b_2^+ f_{2\sigma}. \quad (6)$$

Two sets of slave-boson (b_1, b_2) and pseudo-fermion ($f_{1\sigma}, f_{2\sigma}$) operators have been introduced, with relative weights α and β to be determined shortly [6]. The commutation algebra, Eq. (3), are recovered provided we require the following:

$$\begin{aligned} (a) \quad & b_1^+ b_1 + \sum_\sigma f_{1\sigma}^+ f_{1\sigma} = p \\ (b) \quad & b_2^+ b_2 + \sum_\sigma f_{2\sigma}^+ f_{2\sigma} = q \\ (c) \quad & d_\sigma^+ d_\sigma = \alpha^2 f_{1\sigma}^+ f_{1\sigma} + \beta^2 f_{2\sigma}^+ f_{2\sigma} \\ (d) \quad & \alpha^2 p + \beta^2 q = 1. \end{aligned} \quad (7)$$

Two positive constants p and q have been introduced in the above relations. The empty state $|e\rangle$ takes on the representation,

$$|e\rangle = (m b_1^+ b_2^+ + \frac{n}{\sqrt{2}} (b_1^+)^2) |0\rangle, \quad (8)$$

where $|0\rangle$ is the vacuum state for the slave boson and the pseudo-fermion operators, and for the singly-occupied state, $|\sigma\rangle = d_\sigma^+ |e\rangle$. This assignment is very different from $|e\rangle = b^+ |0\rangle$ and $|\sigma\rangle = f_\sigma^+ |0\rangle$ of the conventional slave-boson theory. Note also that the expression for the empty state is asymmetric in the interchange of b_1 and b_2 [7]. Later we will see that this asymmetry is a consequence of the finite bias across the dot.

The tunnelling part of the Hamiltonian factorizes, $H_T = H_{T1} + H_{T2}$, with the 1 and 2 parts containing the 1- or 2-dependent portion of the d -level operator. We replaced the b -operators by their mean-field values b_1 and b_2 that are assumed to be real. Keldysh techniques are employed in evaluating the averages [2,4]. At zero temperature, the

In order to ensure that the new Hamiltonian expressed in terms of slave bosons and pseudo-fermions has the same matrix elements as the original H , we further require that $\langle \sigma | d_\sigma^+ | e \rangle = 1$ in the new representation. In meeting this requirement, and (a)-(b) of Eq. (7), we deduce several relations: (1) $p = 1 + \kappa$, $q = 1 - \kappa$, (2) $m^2 = 1 - \kappa$, $n^2 = \kappa$, (3) $\alpha^2 = \beta^2 = 1/2$. Now the d -level operator in Eq. (6) is uniquely defined as $d_\sigma = (b_1^+ f_{1\sigma} + b_2^+ f_{2\sigma})/\sqrt{2}$. The value of κ will be determined later.

Hamiltonian in the slave-boson representation becomes

$$\begin{aligned} H_T = & \frac{V_L}{\sqrt{2}} \sum_{k \in L, \sigma} c_{Lk\sigma}^+ (b_1^+ f_{1\sigma} + b_2^+ f_{2\sigma}) + h.c. \\ & + \frac{V_R}{\sqrt{2}} \sum_{k \in R, \sigma} c_{Rk\sigma}^+ (b_1^+ f_{1\sigma} + b_2^+ f_{2\sigma}) + h.c., \end{aligned} \quad (9)$$

and

$$H_d = -\frac{\epsilon_d}{2} \sum_\sigma (f_{1\sigma}^+ f_{1\sigma} + f_{2\sigma}^+ f_{2\sigma}). \quad (10)$$

The complete Hamiltonian together with the occupation constraints given in Eq. (7)(a)-(b) becomes

$$\begin{aligned} H = & H_L + H_R + H_d + H_T \\ & + \lambda_1 \left(b_1^+ b_1 + \sum_\sigma f_{1\sigma}^+ f_{1\sigma} - 1 - \kappa \right) \\ & + \lambda_2 \left(b_2^+ b_2 + \sum_\sigma f_{2\sigma}^+ f_{2\sigma} - 1 + \kappa \right). \end{aligned} \quad (11)$$

In the following we absorb $\sqrt{2}$ in the definition of the tunnelling amplitudes, V_L and V_R .

We have accomplished an *exact mapping* of the original Hamiltonian, Eq. (2), to an equivalent one, Eq. (11), using the slave-boson theory valid in $U \rightarrow \infty$ limit. Although the one-slave-boson theory of AL also starts from an exact mapping of the original Hamiltonian [4], the outcome of the mean-field analysis may differ significantly depending on the type of mapping chosen.

One can carry out the stationary-state analysis of the ground state of the above Hamiltonian in the manner of AL, solving for the four parameters, b_1 , b_2 and λ_1 and λ_2 , which requires

$$b_{1(2)}^2 + \langle \sum_\sigma f_{1(2)\sigma}^+ f_{1(2)\sigma} \rangle = 1 \pm \kappa, \quad (12)$$

and

$$2\lambda_{1(2)} b_{1(2)}^2 + \langle H_{T1(2)} \rangle = 0. \quad (13)$$

mean-field conditions of Eqs. (12) and (13) turn into

$$\begin{aligned}\frac{\pi}{2}(b_1^2 - \kappa) &= \frac{\Gamma_L}{\Gamma_L + \Gamma_R} \arctan\left(\frac{\lambda_1 - \mu_L}{b_1^2 \Sigma_2}\right) + \frac{\Gamma_R}{\Gamma_L + \Gamma_R} \arctan\left(\frac{\lambda_1 - \mu_R}{b_1^2 \Sigma_2}\right), \\ \frac{\pi}{2}(b_2^2 + \kappa) &= \frac{\Gamma_L}{\Gamma_L + \Gamma_R} \arctan\left(\frac{\lambda_2 - \mu_L}{b_2^2 \Sigma_2}\right) + \frac{\Gamma_R}{\Gamma_L + \Gamma_R} \arctan\left(\frac{\lambda_2 - \mu_R}{b_2^2 \Sigma_2}\right),\end{aligned}\quad (14)$$

and

$$\begin{aligned}\epsilon_d &= \Gamma_L \ln\left(\frac{D^2}{(\lambda_1 - \mu_L)^2 + (b_1^2 \Sigma_2)^2}\right) + \Gamma_R \ln\left(\frac{D^2}{(\lambda_1 - \mu_R)^2 + (b_1^2 \Sigma_2)^2}\right), \\ \epsilon_d &= \Gamma_L \ln\left(\frac{D^2}{(\lambda_2 - \mu_L)^2 + (b_2^2 \Sigma_2)^2}\right) + \Gamma_R \ln\left(\frac{D^2}{(\lambda_2 - \mu_R)^2 + (b_2^2 \Sigma_2)^2}\right).\end{aligned}\quad (15)$$

We have introduced $\Gamma_L = V_L^2 \rho_L$, $\Gamma_R = V_R^2 \rho_R$, the width of the conduction band D , the self-energy $\Sigma_2 = \pi(\Gamma_L + \Gamma_R)$, and re-defined $\lambda_{1(2)} - \epsilon_d + b_{1(2)}^2 \Sigma_1$ as $\lambda_{1(2)}$ in the above expressions. $\Sigma = \Sigma_1 + i\Sigma_2$ gives the complex self-energy of the d -electron due to hybridization with the leads. We consider the case $\epsilon_d \gg \lambda_{1(2)}, |\Sigma|$, as would be appropriate for the Kondo regime.

Equations (14)-(15) are the central results of this paper. In the following we solve them for the case of symmetric coupling, $\Gamma_L = \Gamma_R$, and in the limit of infinite barrier to one of the leads, $\Gamma_R \rightarrow 0$.

The bias voltage $\mu_R - \mu_L = V$ is taken to be positive (right lead at higher chemical potential than the left lead). We look for solutions in the Kondo limit $b_1^2 \approx 0 \approx b_2^2$, and λ_1 and λ_2 lying very close to either μ_L or μ_R . The case $\lambda_1 \approx \lambda_2$ has a solution only for a small bias, $V \ll b^2 \Sigma_2$ and is not applicable at large V . Hence we require that $\lambda_1 \approx \mu_L$, and $\lambda_2 \approx \mu_R$. The other possibility, $\lambda_1 \approx \mu_R$ and $\lambda_2 \approx \mu_L$, is obtained when the bias is reversed, $V < 0$.

The self-consistency equations are now reduced to (taking $\Gamma_L = \Gamma_R$)

$$\begin{aligned}b_1^2 &\approx b_0^2/[1 + \pi^2(b_0^2 - \kappa')^2]^{1/2} \\ b_2^2 &\approx b_0^2/[1 + \pi^2(b_0^2 + \kappa')^2]^{1/2},\end{aligned}\quad (16)$$

where $\kappa' = \kappa - (1/\pi) \arctan[V/b_0^2 \Sigma_2]$, and

$$b_0^2 \Sigma_2 \approx \frac{D^2}{\max(V, b_0^2 \Sigma_2)} e^{-\pi \epsilon_d / \Sigma_2}, \quad (17)$$

while $\lambda_1 - \mu_L$ and $\lambda_2 - \mu_R$ satisfy

$$\lambda_{1(2)} - \mu_{L(R)} \approx \pi b_{1(2)}^2 \Sigma_2 \times [b_{1(2)}^2 - \kappa']. \quad (18)$$

Now we come to the determination of κ . It is chosen to minimize the energy $\langle H_T + H_d \rangle$ which, after self-consistent relations Eqs. (12) and (13) are taken into account, become $-\frac{1}{2}\epsilon_d(b_1^2 + b_2^2) + \text{const.}$ Other terms in the expectation value of the Hamiltonian are insensitive to the choice of κ . Optimal κ is therefore one that maximizes $b_1^2 + b_2^2$. Given the expressions for b_1^2 and b_2^2 obtained in Eq. (16), it immediately follows that κ' must be zero, or $\kappa = \arctan[V/b_0^2 \Sigma_2]$. Since the empty state

$|e\rangle$ is defined as $(\sqrt{1 - \kappa} b_1^+ b_2^+ + \sqrt{\kappa/2} (b_1^+)^2)|0\rangle$, we see that the definition of the state itself depends on the applied bias! Put another way our expression for the empty state contains a variational parameter κ , which is chosen to maximize the energy gain from the hybridization.

The mean-field solution demonstrates the existence of two Kondo peaks since the d -electron spectral function is given by the sum

$$A_d(\omega) \approx \frac{b_1^2}{2} A_1(\omega) + \frac{b_2^2}{2} A_2(\omega) \quad (19)$$

with the spectral functions for the pseudo-fermions f_1 ($A_1(\omega)$) and f_2 ($A_2(\omega)$) each producing a resonance at the chemical potential of the lead [8].

The magnitude of $b_0^2 \Sigma_2$ is the so-called Kondo temperature, T_K . One can see from Eq. (17) that T_K changes as the bias voltage is increased through the threshold value, $V = D e^{-\pi \epsilon_d / 2 \Sigma_2} \equiv T_K^*$ in the manner

$$\begin{aligned}T_K &\approx T_K^* & (V < T_K^*) \\ &\approx (T_K^*)^2 / V & (V > T_K^*).\end{aligned}\quad (20)$$

Coleman *et al.* [9] made a similar prediction for the crossover behavior of the Kondo scale as the bias voltage is increased through T_K^* , based on the perturbative calculation of the magnetic susceptibility. Our mean-field calculation demonstrates the crossover behavior explicitly. The crossover scale T_K^* is the Kondo temperature at equilibrium.

When tunnelling to one of the barriers is forbidden, $\Gamma_R \rightarrow 0$, we have as the solution $\kappa = 0$, $b_0^2 \Sigma_2 = T_K^*$, and $\lambda_1 = \lambda_2 \approx \mu_L$. Therefore, the two spectral functions $A_1(\omega)$ and $A_2(\omega)$ merge to produce a single resonance peak at μ_L , as one would expect in the case of coupling to a single reservoir. Further calculation (see next paragraph) shows that the split resonance positions are close to the chemical potentials of each reservoir as long as the

tunnelling strengths, given by Γ_L and Γ_R , are reasonably close to each other. As Γ_R/Γ_L becomes too small, eventually the resonance level pinned to μ_R begins to float, and merge with μ_L .

When $V \gg T_K^*$, some understanding can be achieved for the slightly asymmetric case, $\Gamma_L + \Gamma_R = \Gamma$, $\Gamma_L - \Gamma_R = \Gamma\epsilon$ with $0 < \epsilon \ll 1$. Here we obtain that the Kondo temperatures scale differently for the two resonances, with the T_K for the stronger resonance near μ_L varying as $T_K^*(T_K^*/V)^{(1-\epsilon)/(1+\epsilon)}$, and for the weaker resonance to the right reservoir, as $T_K^*(T_K^*/V)^{(1+\epsilon)/(1-\epsilon)}$. In the highly asymmetric case, *i.e.* $\Gamma_L = \Gamma(1 - \epsilon)$ and $\Gamma_R = \Gamma\epsilon$, we get the Kondo temperature scaling $T_K^*(T_K^*/V)^{\epsilon/(1-\epsilon)}$ for both resonances. Predicting such dependence of power-law exponents on the tunnelling geometry would be very difficult based on other calculation schemes, and illustrates the utility of SBMFT. It is of course an interesting issue to see if experimentally such power-law behavior indeed shows up.

In conclusion, we have introduced a new version of SBMFT for the Kondo effect in a quantum dot that correctly reproduce the equilibrium Kondo effect, and interpolates smoothly to the non-equilibrium situation with a bias V or to the case of asymmetric coupling to the reservoirs. The introduction of two sets of slave-bosons and pseudo-fermions may at first sight seem to have doubled the number of orbitals in the dot, but on closer inspection it is clear that the dimension of the Hilbert space for the dot is strictly three, as ought to be the case for $U \rightarrow \infty$. Rather, we believe this doubling of the number of operators is tied to the presence of multiple reservoirs with which the dot's electron can interact. Meanwhile, the technical aspect of the present theory is completely straightforward and may be easily generalized to understand Kondo physics in other, more complex situations with multiple dots [4], a phonon-coupled dot [10], *etc.* Also of great interest is the role of the inelastic processes, not considered in the present mean-field theory, in reducing the Kondo scale T_K [11]. Future work will address these issues.

We acknowledge helpful discussions with Kicheon Kang, Tae-Suk Kim, Hyun-Woo Lee, and Heung-Sun Sim. The completion of the paper took place during participation at the APCTP Focus Program "Quantum Effects in Nanosystems". This research is supported by Korea Research Foundation Grant (KRF-2002-003-C00042) and by Korean Science and Engineering Foundation (KOSEF) through Center for Strongly Correlated Materials Research (CSCMR) at Seoul National University.

-
- [1] Jiwoong Park *et al.*, Nature **417**, 722 (2002); Wenjie Liang *et al.*, Nature **417**, 725 (2002).
 - [2] Y. Meir, Ned S. Wingreen, and Patrick A. Lee, Phys. Rev. Lett. **70**, 2601 (1993); Ned S. Wingreen and Yigal Meir, Phys. Rev. B **49**, 11040 (1994).
 - [3] A. C. Hewson, *The Kondo Problem to Heavy Fermions* (Cambridge University Press, Cambridge, U.K., 1993).
 - [4] Ramón Aguado and David C. Langreth, Phys. Rev. Lett. **85**, 1946 (2000).
 - [5] An experiment in support of the splitting of the Kondo resonance at finite bias is carried out in S. De Franceschi *et al.*, Phys. Rev. Lett. **89**, 156801 (2002).
 - [6] In the coupling of N leads to the dot, one can presumably write d_σ as a sum, $\sum_{i=1}^N \alpha_i b_i^+ f_{i\sigma}$ ($\sum_i \alpha_i^2 = 1$). We restrict ourselves to $N = 2$ in this paper.
 - [7] One can equally well have written $|e\rangle = (mb_1^+ b_2^+ + \frac{n}{\sqrt{2}}(b_2^+)^2)|0\rangle$ without a loss of generality.
 - [8] One can show that the cross terms such as $\langle f_{1\sigma}^+ f_{2\sigma} \rangle$ are $O(b_0^2)$ smaller than the direct terms shown in Eq. (19).
 - [9] P. Coleman, C. Hooley, O. Parcollet, Phys. Rev. Lett. **86**, 4088 (2001).
 - [10] Lam H. Yu and Douglas Natelson, cond-mat/0310625.
 - [11] A. Kaminski, Yu V. Nazarov, and L. I. Glazman, Phys. Rev. Lett. **83**, 384 (1999); A. Rosch, J. Kroha, and P. Wölfle, Phys. Rev. Lett. **87**, 156802 (2001).